TOSHIBA

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2412,RN2413

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

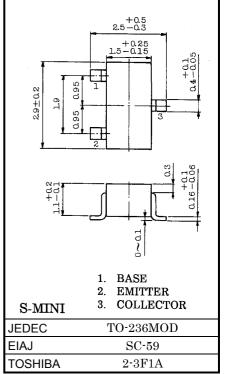
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1412, RN1413

Equivalent Circuit

Maximum Ratings (Ta = 25°C)

Characterisstic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	IC	-100	mA
Collector power dissipation	PC	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Unit in mm



Weight: 0.012g

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In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

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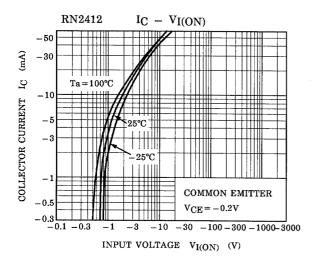
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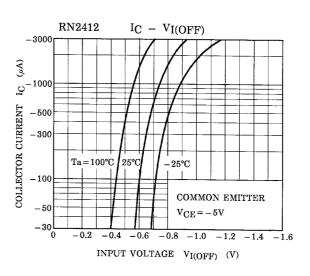
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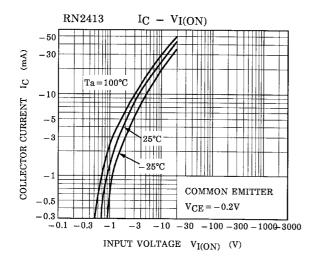


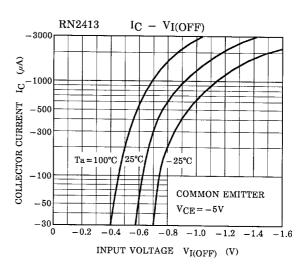
Electrical Characteristics (Ta = 25°C)

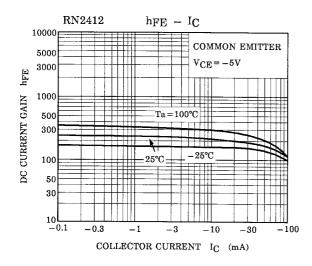
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	_	$V_{CB} = -50V$, $I_E = 0$	_	_	-100	nA
Emitter cut-off current		I _{EBO}	_	$V_{EB} = -5V, I_C = 0$	_	_	-100	nA
DC current gain		h _{FE}	_	$V_{CE} = -5V, I_{C} = -1mA$	120	_	400	-
Collector-emitter saturation voltage		V _{CE} (sat)	_	$I_C = -5mA$, $I_B = -0.25mA$	_	-0.1	-0.3	V
Translation frequency		f _T	_	$V_{CE} = -10V, I_{C} = -5mA$	_	250	_	MHz
Collector output capacitan	ce	C _{ob}	_	$V_{CB} = -10V$, $I_E = 0$, $f = 1MHz$	_	3	6	pF
Input resistor	RN2412	- R1	_	_	15.4	22	28.6	kΩ
	RN2413				32.9	47	61.1	

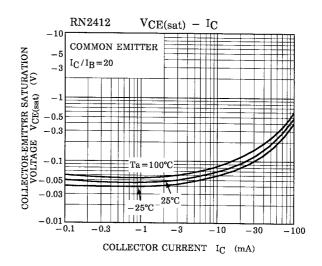


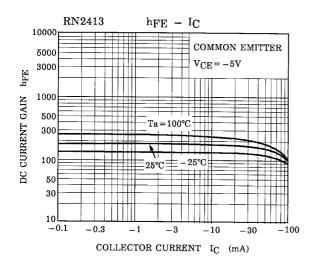


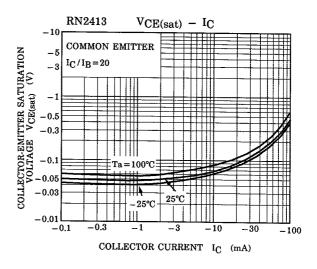


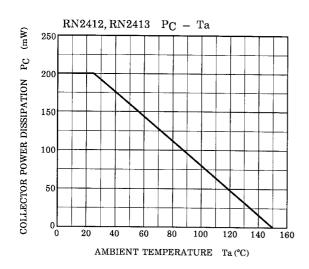












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Type Name	Marking	
RN2412	Type Name Y N	
RN2413	Type Name YP	